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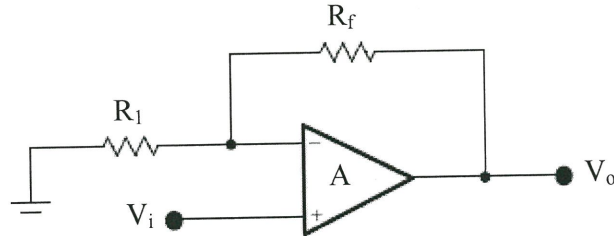
UNIVERSITI TUN HUSSEIN ONN MALAYSIA

**FINAL EXAMINATION
SEMESTER I
SESSION 2013/2014**

COURSE NAME : ELECTRONICS II
COURSE CODE : BWC 20203
PROGRAMME : 2 BWC
EXAMINATION DATE : DECEMBER 2013 / JANUARY 2014
DURATION : 3 HOURS
INSTRUCTION : ANSWER **ALL** QUESTIONS

THIS QUESTION PAPER CONSISTS OF **SIX (6)** PAGES

- Q1** (a) Determine three advantages of integrated circuit (ICs) over conventional circuit. (6 marks)
- (b) Determine the voltage gain for the circuit shown in Figure Q1, with $R_f = 100 \text{ K}\Omega$ and $R_1 = 10 \text{ K}\Omega$.

**FIGURE Q1**

- (c) In an amplifier with negative feedback, the gain of basic amplifier is 100 and it employs a feedback factor of 0.02. If the input signal is 40mV, determine, (4 marks)
- (i) Voltage gain with feedback (2 marks)
- (ii) Output voltage (2 marks)
- (d) A negative feedback of $\beta = 2.5 \times 10^{-3}$ is applied to an amplifier of open loop gain 1000. Calculate the change in overall gain of the feedback amplifier if the gain of the internal amplifier is reducing by 20%. (6 marks)

- Q2** (a) Figure Q2 shows inverting op-amp circuit. The op-amp has an open loop gain, $\mu = 10^4 \text{ V/V}$, $R_{id} = 100 \text{ k}\Omega$ and $r_o = 1 \text{ k}\Omega$. By using shunt-shunt feedback method, calculate; (6 marks)
- (i) the voltage gain, V_o/V_s . (4 marks)
- (ii) input resistance, R_{in} . (4 marks)
- (iii) output resistance, R_{out} . (6 marks)

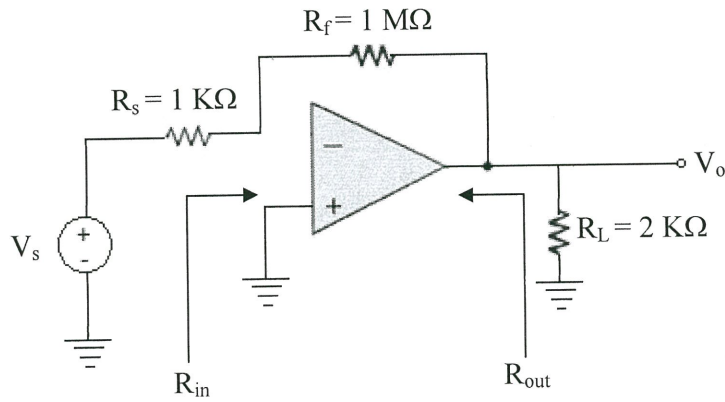


FIGURE Q2

- (b) State three differences between Field Effect Transistor (FET) and Bipolar Junction Transistor (BJT). (6 marks)

Q3 (a) Write the circuit of current mirror used in an op-amp design and explain its operation. (8 marks)

(b) Figure Q3 (a) and Figure Q3 (b) shows a base current compensation current mirror and Wilson mirror configuration respectively. Describe,

- (i) The equation for output current for both configurations. (6 marks)
- (ii) The equation for output resistance for both configurations. (6 marks)

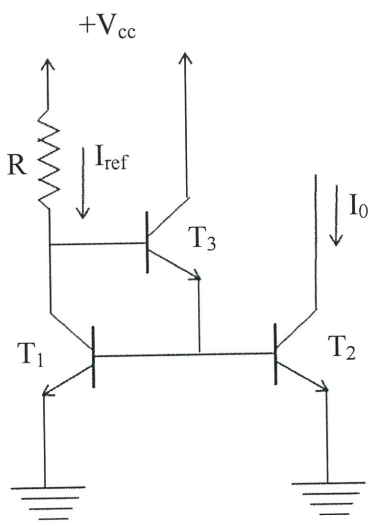


FIGURE Q3 (a)

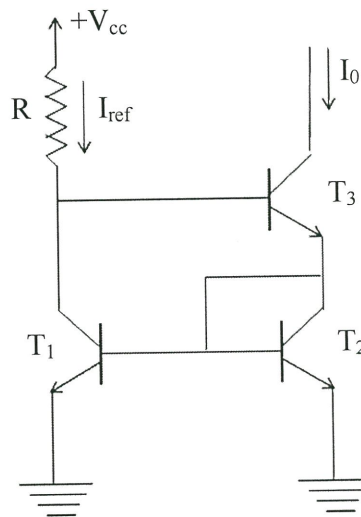


FIGURE Q3 (b)

Q4 (a) The transistors in the differential amplifier circuit shown in Figure **Q4 (a)** have an identical characteristics and their $\beta = 100$. Given $V_{BE} = 0.7$ V, determine,

- (i) Output voltage (2 marks)
- (ii) Base currents (3 marks)
- (iii) Base voltages taking into account the effect of the R_B and V_{BE} . (3 marks)

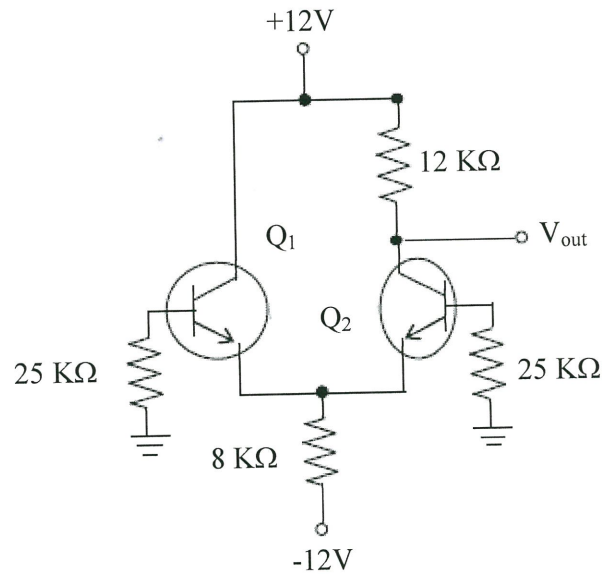


FIGURE Q4

- (b) i. Describe a 'multistage amplifier' (2 marks)
- ii. Give two requirements to be fulfilled for an ideal coupling network. (4 marks)
- (c) Calculate the capacitance values required to produce a 3 kHz critical frequency in the low pass filter as in Figure **Q4 (b)**. (6 marks)

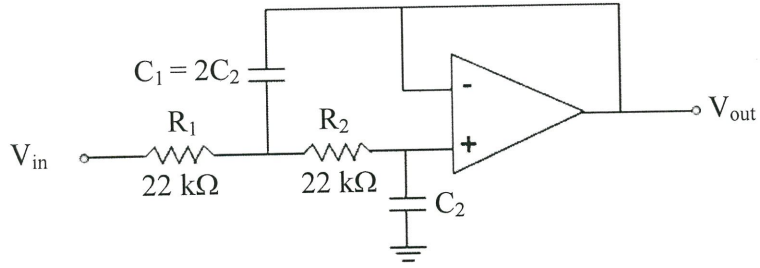


FIGURE Q4 (b)

Q5 (a) Figure **Q5 (a)** shows a circuit for the combination of high pass and low pass filter. Determine,

- i. the bandwidth of the circuit (4 marks)
- ii. center of the frequency (4 marks)

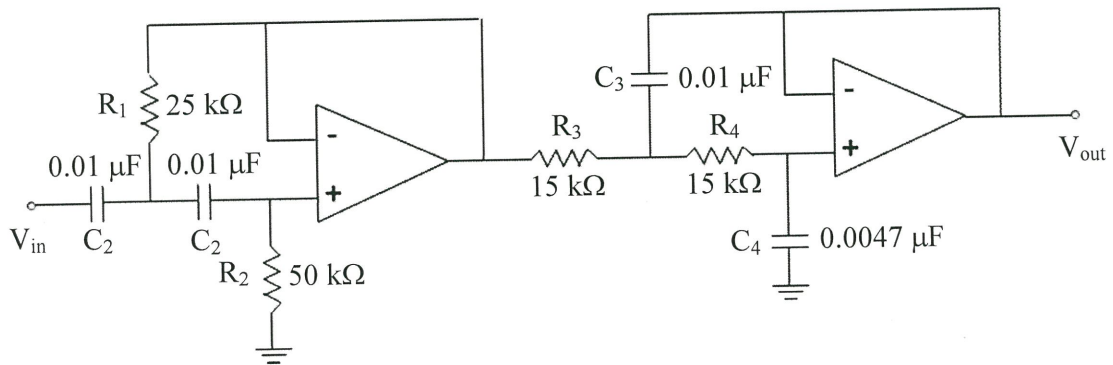


FIGURE Q5 (a)

(b) A digital high pass infinite impulse response (IIR) filter is required to fulfill the specifications given in Figure **Q5 (b)**. The sampling frequency F_s is 8:0 kHz. The filter is to be designed with Chebyshev filter using bilinear transformation method.

- (i) Calculate the order of the filter. (6 marks)
- (ii) Determine the system function $H(z)$ of the filter. (6 marks)

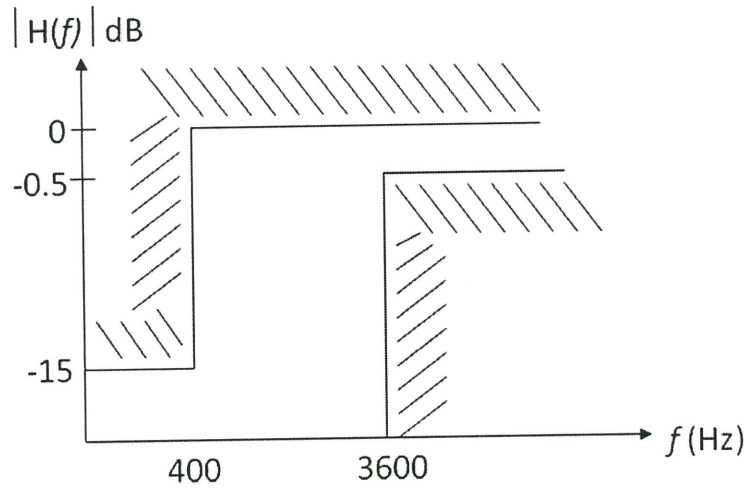


FIGURE Q5 (b)

END OF QUESTION